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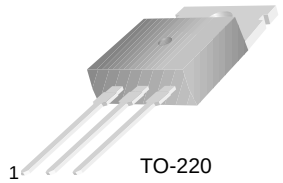
KSA1010

High Speed High Voltage Switching

- Industrial Use
- Complement to KSC2334



TO-220

1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	- 100	V
V_{CEO}	Collector-Emitter Voltage	- 100	V
V_{EBO}	Emitter-Base Voltage	- 7	V
I_C	Collector Current (DC)	- 7	A
I_{CP}	*Collector Current (Pulse)	- 15	A
I_B	Base Current	- 3.5	A
P_C	Collector Dissipation (T_C=25°C)	40	W
	Collector Dissipation (T_a=25°C)	1.5	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 55 ~ 150	°C

* PW≤300μs, Duty Cycle≤10%

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Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage	I_C = - 5A, I_{B1} = - 0.5A, L = 1mH	- 100		V
V_{CEX}(sus)1	Collector-Emitter Sustaining Voltage	I_C = - 5A, I_{B1} = - I_{B2} = - 0.5A V_{BE}(off) = 5V, L = 180μH Clamped	- 100		V
V_{CEX}(sus)2	Collector-Emitter Sustaining Voltage	I_C = - 10A, I_{B1} = - 1A I_{B2} = 0.5A, V_{BE}(off) = 5V L = 180μH, Clamped	- 100		V
I_{CBO}	Collector Cut-off Current	V_{CB} = - 100V, I_E = 0		- 10	μA
I_{CER}	Collector Cut-off Current	V_{CE} = - 100V, R_{BE} = 51Ω T_C = 125°C		- 1	mA
I_{CEX1}	Collector Cut-off Current	V_{CE} = - 100V, V_{BE}(off) = 1.5V		- 10	μA
I_{CEX2}	Collector Cut-off Current	V_{CE} = - 100V, V_{BE}(off) = 1.5V T_C = 125°C		- 1	mA
I_{EBO}	Emitter Cut-off Current	V_{EB} = - 5V, I_C= 0		- 10	uA
h_{FE1} h_{FE2} h_{FE3}	* DC Current Gain	V_{CE} = - 5V, I_C = - 0.5A V_{CE} = - 5V, I_C = - 3A V_{CE} = - 5V, I_C = - 5A	40 40 20	200	
V_{CE}(sat)	* Collector-Emitter Saturation Voltage	I_C = - 5A, I_B = - 0.5A		- 0.6	V
V_{BE}(sat)	* Base-Emitter Saturation Voltage	I_C = - 5A, I_B = - 0.5A		- 1.5	V
t_{ON}	Turn On Time	V_{CC} = - 50V, I_C = - 5A, I_{B1} = - I_{B2} = - 0.5A R_L = 10Ω		0.5	μs
t_{STG}	Storage Time			1.5	μs
t_F	Fall Time			0.5	μs

Pulse Test: PW≤350μs, Duty Cycle≤2%

h_{FE} Classification

Classification	R	O	Y
h_{FE2}	40 ~ 80	60 ~ 120	100 ~ 200

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Typical Characteristics

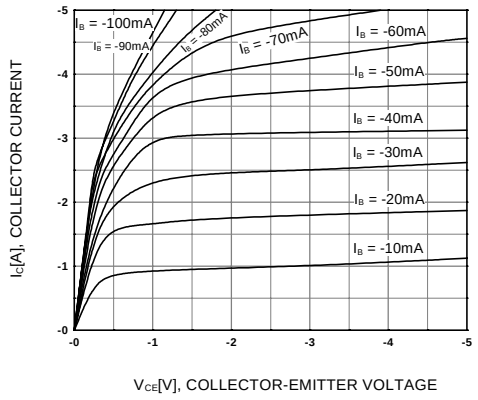

Figure 1. Static Characteristic

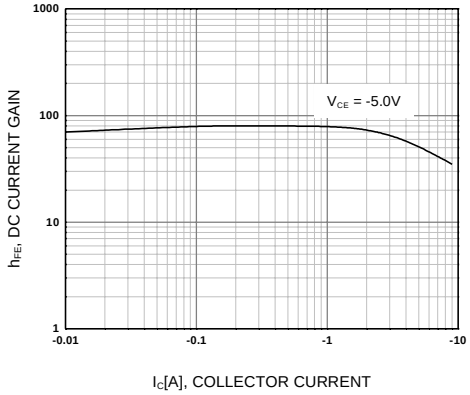

Figure 2. DC current Gain

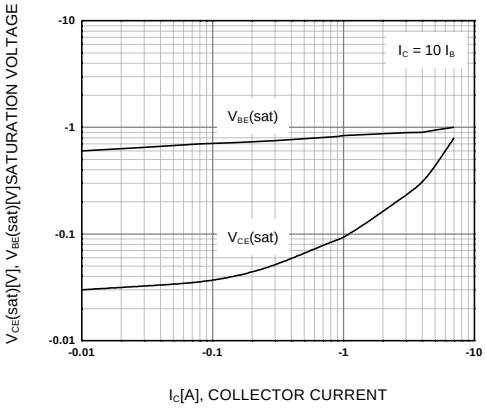

Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

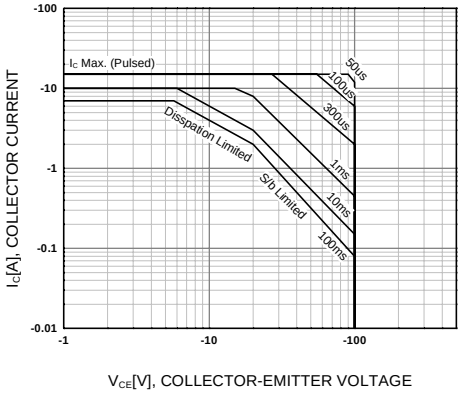

Figure 4. Safe Operating Area

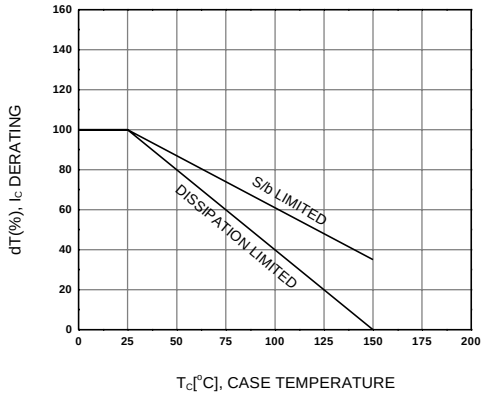

Figure 5. Derating Curve of Safe Operating Areas

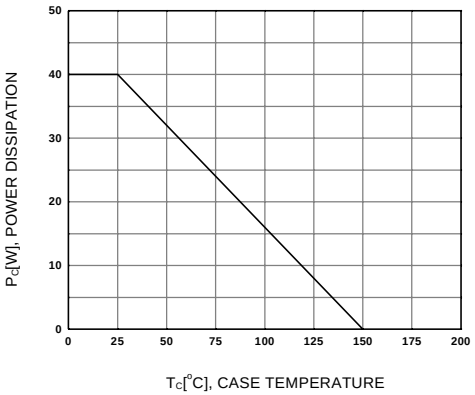

Figure 6. Power Derating

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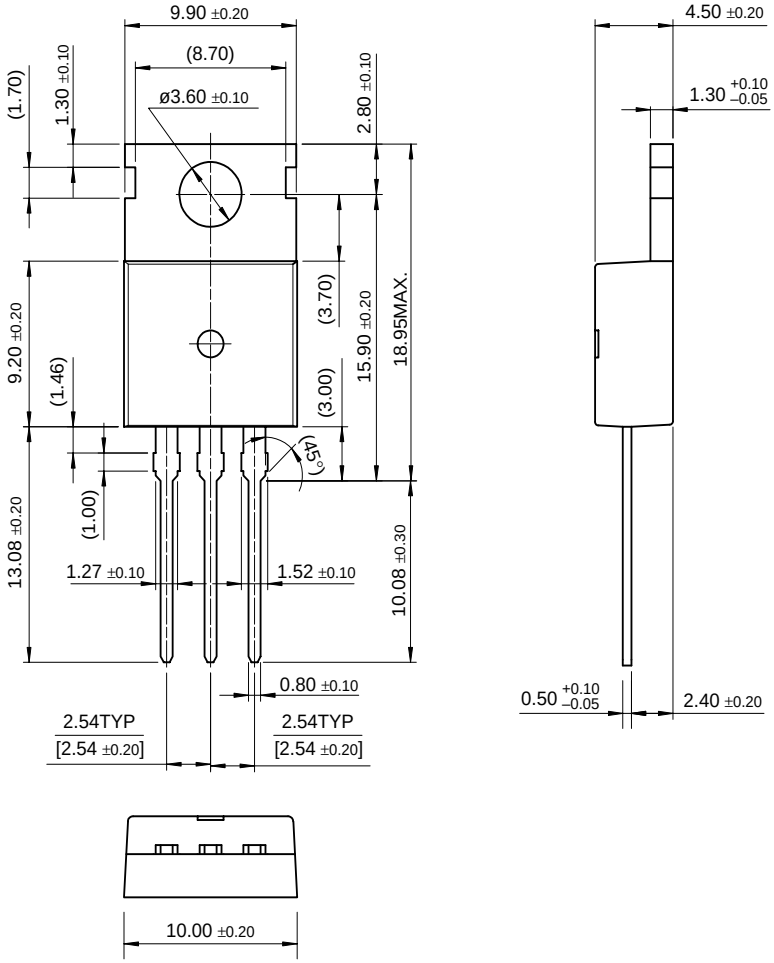
Package Demensions

TO-220



Dimensions in Millimeters

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